BLC9G20LS-361AVT

Power LDMOS transistor Rev. 1 — 25 February 2016

AMMPLEON

Product data sheet

Product profile 1.

1.1 General description

360 W LDMOS packaged asymmetric Doherty power transistor for base station applications at frequencies from 1805 MHz to 1990 MHz.

Typical performance

Typical RF performance at T_{case} = 25 °C in an asymmetrical Doherty demo circuit. V_{DS} = 28 V; I_{Dq} = 400 mA (main); $V_{GS(amp)peak}$ = 0.7 V, unless otherwise specified.

Test signal	f	V _{DS}	P _{L(AV)}	G _p	η_D	ACPR
	(MHz)	(V)	(dBm)	(dB)	(%)	(dBc)
1-carrier W-CDMA	1805 to 1880	28	47.8	16.4	50	-30 <u>[1]</u>

^[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 7.2 dB at 0.01% probability on CCDF per carrier.

Table 2. Typical performance

Typical RF performance at T_{case} = 25 °C in an asymmetrical Doherty demo circuit. V_{DS} = 28 V; I_{Dq} = 450 mA (main); $V_{GS(amp)peak}$ = 0.6 V, unless otherwise specified.

Test signal	f	V _{DS}	$P_{L(AV)}$	G_p	η_D	ACPR
	(MHz)	(V)	(dBm)	(dB)	(%)	(dBc)
1-carrier W-CDMA	1930 to 1990	28	47.8	16.6	47.5	-35 <u>[1]</u>

^[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 7.2 dB at 0.01% probability on CCDF per carrier.

1.2 Features and benefits

- Excellent ruggedness
- High-efficiency
- Low thermal resistance providing excellent thermal stability
- Designed for broadband operation (1805 MHz to 1990 MHz)
- Asymmetric design to achieve optimum efficiency across the band
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

RF power amplifiers for base stations and multi carrier applications in the 1805 MHz to 1990 MHz frequency range

2. Pinning information

Table 3. Pinning

Pin	Description		Simplified outline	Graphic symbol
1	drain2 (peak)		- 0 4 -	0.7
2	drain1 (main)		7 2 1 6	2,7
3	gate1 (main)		5	<u> </u>
4	gate2 (peak)		3 4	3——5
5	source	[1]		4—
6	video decoupling (peak)			'
7	video decoupling (main)			1, 6 aaa-014884

^[1] Connected to flange.

3. Ordering information

Table 4. Ordering information

Type number	Packag	Package				
	Name	Description	Version			
BLC9G20LS-361AVT	-	air cavity plastic earless flanged package; 6 leads	SOT1258-3			

4. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V _{GS(amp)main}	main amplifier gate-source voltage		-5	+13	V
V _{GS(amp)peak}	peak amplifier gate-source voltage		-5	+13	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	<u>[1]</u>	-	225	°C

Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}		V_{DS} = 28 V; I_{Dq} = 400 mA (main); $V_{GS(amp)peak}$ = 0.5 V; T_{case} = 80 °C		
		P _L = 47.5 dBm	0.26	K/W
		P _L = 49.5 dBm	0.19	K/W

6. Characteristics

Table 7. DC characteristics

 T_i = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Main dev	rice					
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 1.2 \text{ mA}$	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 120 mA	1.5	2.0	2.5	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 28 V; I_{D} = 400 mA	1.65	2.25	2.85	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 32 V	-	-	2.8	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	26	-	Α
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	280	nA
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 0.12 A	-	1.27	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 4.2 \text{ A}$	-	120	198	mΩ
Peak dev	rice					
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 2.2 \text{ mA}$	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 220 mA	1.5	2.0	2.5	V
V_{GSq}	gate-source quiescent voltage	V _{DS} = 28 V; I _D = 1000 mA	1.55	2.15	2.75	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 32 V	-	-	2.8	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	48	-	Α
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	280	nA
9 _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 0.22 A	-	2.32	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 7.7 \text{ A}$	-	65	112	mΩ

Table 8. RF characteristics

Specifications are tested with test signal: 1-carrier W-CDMA; PAR = 7.2 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1 to 64 DPCH; f_1 = 1805 MHz; f_2 = 1880 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 300 mA (main); $V_{GS(amp)peak}$ = 0.5 V; T_{case} = 25 °C; unless otherwise specified; in an asymmetrical Doherty production test circuit at frequencies from 1805 MHz to 1880 MHz.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	$P_{L(AV)} = 47.5 \text{ dBm}$	14.5	15.7	-	dB
RLin	input return loss	$P_{L(AV)} = 47.5 \text{ dBm}$	-	-9	-5	dB
η_{D}	drain efficiency	$P_{L(AV)} = 47.5 \text{ dBm}$	42.5	47.5	-	%
ACPR	adjacent channel power ratio	P _{L(AV)} = 47.5 dBm	-	-31	-26	dBc

7. Test information

7.1 Ruggedness in Doherty operation

The BLC9G20LS-361AVT is capable of withstanding a load mismatch corresponding to a VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dq} = 400 mA; $V_{GS(amp)peak}$ = 0.5 V; P_{L} = 120 W (CW); f = 1805 MHz; tested on the Doherty development test circuit.

7.2 Impedance information

Table 9. Typical impedance of main device Measured load-pull data of main device; $I_{Dq} = 720 \text{ mA}$; $V_{DS} = 28 \text{ V}$.

f	Z _S [1]	Z _L [1]	P _L [2]	η _D [2]	G _p [3]			
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)			
Maximum po	Maximum power load							
1805	1.0 - j4.0	1.4 – j3.5	155	57.5	18.4			
1843	1.4 – j3.9	1.4 – j3.5	151	57.1	18.0			
1880	1.1 – j4.1	1.4 – j3.5	151	57.1	18.5			
Maximum dra	in efficiency load							
1805	1.0 - j4.0	2.8 - j2.0	104	69.0	20.9			
1843	1.4 – j3.9	2.6 – j1.8	102	69.1	20.5			
1880	1.1 – j4.1	2.4 – j2.1	106	68.3	21.0			

^[1] Z_S and Z_L defined in Figure 1.

Table 10. Typical impedance of peak device

Measured load-pull data of peak device; $I_{Dq} = 1320 \text{ mA}$; $V_{DS} = 28 \text{ V}$.

f	Z _S [1]	Z _L [1]	P _L [2]	η _D [2]	G _p [3]			
(MHz)	(Ω)	(Ω)	(W)	(%)	(dB)			
Maximum pov	Maximum power load							
1805	0.9 – j4.8	2.3 – j3.6	262	55.3	19.2			
1843	1.8 – j4.9	2.3 – j3.6	256	54.7	18.7			
1880	1.5 – j5.4	2.3 – j3.6	254	54.6	19.3			
Maximum dra	in efficiency load							
1805	0.9 – j4.8	3.4 – j1.5	183	64.2	21.5			
1843	1.8 – j4.9	3.1 – j1.4	176	63.5	21.1			
1880	1.5 – j5.4	2.7 – j1.5	179	63.1	21.6			

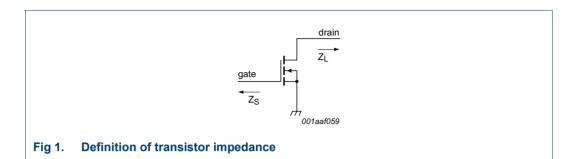
^[1] Z_S and Z_L defined in Figure 1.

^{[2] 0.3} dB power back off from 3 dB compression points.

^{[3] 6.0} dB power back off from 3 dB compression points.

^{[2] 0.3} dB power back off from 3 dB compression points.

^{[3] 6.0} dB power back off from 3 dB compression points.



7.3 Test circuit

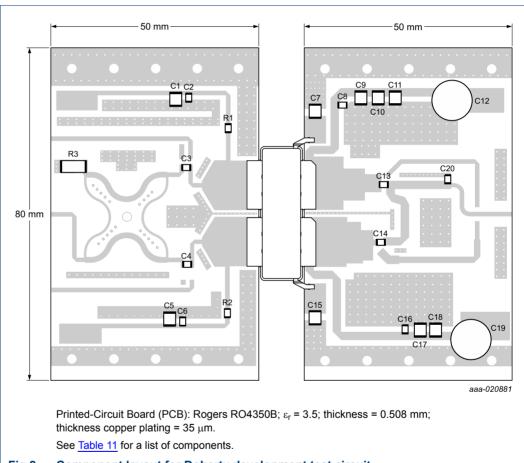


Fig 2. Component layout for Doherty development test circuit

Table 11. List of components See Figure 2 for component layout.

Component	Description	Value	Remarks
-	multilayer ceramic chip capacitor	10 μF, 50 V	Murata
C2, C3, C4, C6, C8, C14, C16	multilayer ceramic chip capacitor	9.1 pF	ATC600F
C12, C19	electrolytic capacitor	2200 μF, 63 V	
C13	multilayer ceramic chip capacitor	8.2 pF	ATC600F

Table 11. List of components ...continued

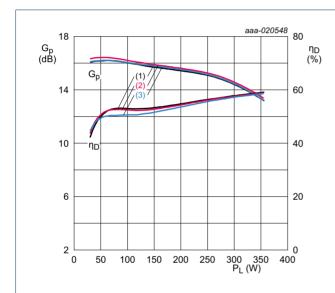
See Figure 2 for component layout.

Component	Description	Value	Remarks
C20	multilayer ceramic chip capacitor	0.5 pF	ATC600F
R1, R2	resistor	5.1 Ω	SMD 0805
R3	resistor	50 Ω	SMD 2512

7.4 Graphical data

All data are measured on the Doherty development test circuit.

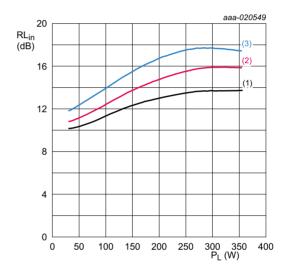
7.4.1 Pulsed CW



 V_{DS} = 28 V; I_{Dq} = 400 mA (main device); $V_{GS(amp)peak}$ = 0.5 V; t_p = 100 μ s; δ = 10 %.

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

Fig 3. Power gain and drain efficiency as function of output power; typical values

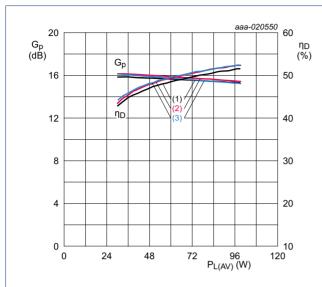


 V_{DS} = 28 V; I_{Dq} = 400 mA (main device); $V_{GS(amp)peak}$ = 0.5 V; t_p = 100 $\mu s;$ δ = 10 %.

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

Fig 4. Input return loss as a function of output power; typical values

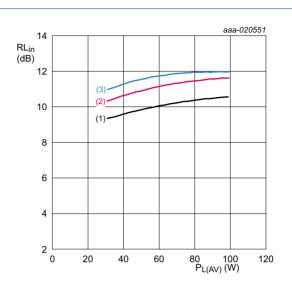
7.4.2 1-Carrier W-CDMA



 V_{DS} = 28 V; I_{Dq} = 400 mA (main device); $V_{GS(amp)peak}$ = 0.5 V.

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

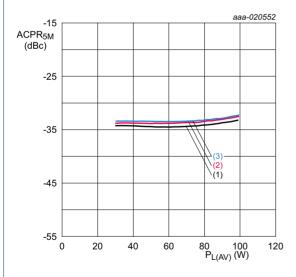
Fig 5. Power gain and drain efficiency as function of average output power; typical values



 V_{DS} = 28 V; I_{Dq} = 400 mA (main device); $V_{GS(amp)peak}$ = 0.5 V.

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

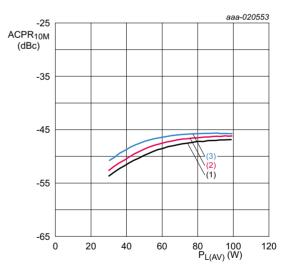
Fig 6. Input return loss as a function of average output power; typical values



 V_{DS} = 28 V; I_{Dq} = 400 mA (main device); $V_{GS(amp)peak}$ = 0.5 V.

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

Fig 7. Adjacent channel power ratio (5 MHz) as a function of average output power; typical values

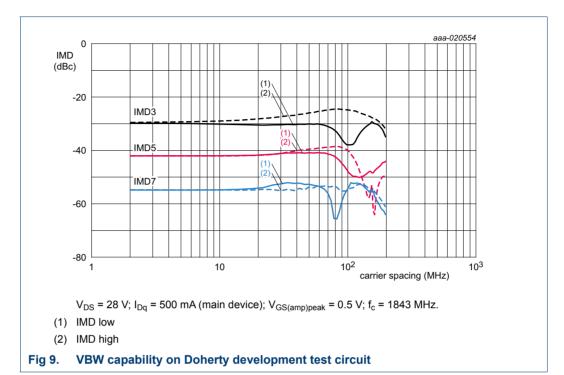


 V_{DS} = 28 V; I_{Dq} = 400 mA (main device); $V_{GS(amp)peak}$ = 0.5 V.

- (1) f = 1805 MHz
- (2) f = 1843 MHz
- (3) f = 1880 MHz

Fig 8. Adjacent channel power ratio (10 MHz) as a function of average output power; typical values

7.4.3 2-Tone VBW



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8. Package outline

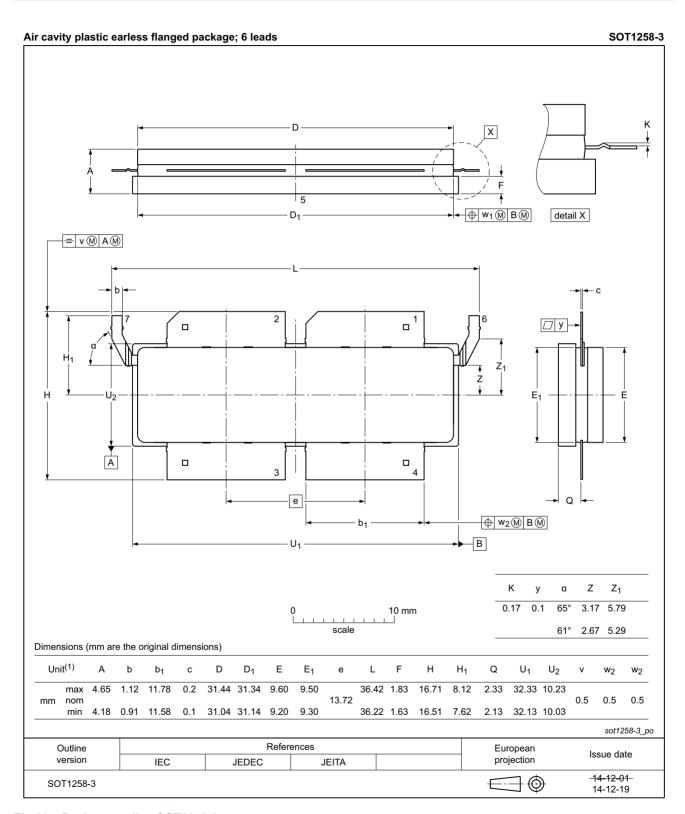


Fig 10. Package outline SOT1258-3

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 12. Abbreviations

Acronym	Description	
3GPP	3rd Generation Partnership Project	
CCDF	Complementary Cumulative Distribution Function	
CW	Continuous Wave	
DPCH	Dedicated Physical CHannel	
ESD	ElectroStatic Discharge	
LDMOS	Laterally Diffused Metal-Oxide Semiconductor	
MTF	Median Time to Failure	
PAR	Peak-to-Average Ratio	
SMD	Surface Mounted Device	
VBW	Video BandWidth	
W-CDMA	Wideband Code Division Multiple Access	

11. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLC9G20LS-361AVT v.1	20160225	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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BLC9G20LS-361AVT

Power LDMOS transistor

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